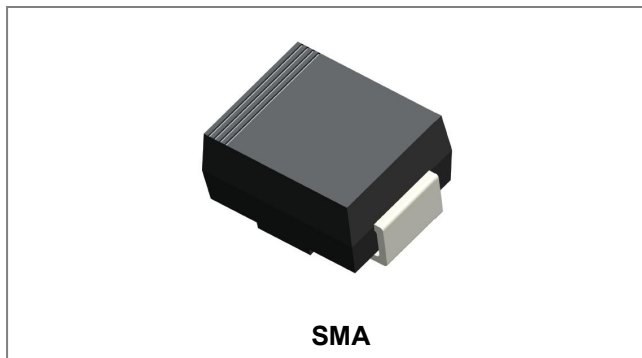


## ES2A-ES2J SURFACE MOUNT SUPER FAST RECTIFIER



### Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Overload Drop, High Efficiency
- Low Power Loss
- Super-Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- Terminals finish: 100% Pure Tin
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Circuit Diagram



### Mechanical Data

- Case: Low Profile Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.06 grams(approx)

### Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	ES2A	ES2B	ES2C	ES2D	ES2E	ES2G	ES2J	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	50	100	150	200	300	400	600	V
RMS Reverse Voltage	$V_{R(RMS)}$	34	70	105	140	210	280	420	
Average Rectified Output Current @ $T_L = 110^\circ\text{C}$	$I_o$	2.0							A
Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	50							A
Forward Voltage @ $I_F = 2.0\text{A}$ , $T_J = 25^\circ\text{C}$	$V_F$	0.95			1.25		1.7		V
Maximum DC reverse current at rated DC blocking voltage $T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	$I_R$	5.0 500							$\mu\text{A}$
Typical junction capacitance (Note 1)	$C_J$	25							pF
Maximum Reverse Recovery Time (Note 2)	$T_{rr}$	35							ns
Typical thermal resistance (Note 3)	$R_{\theta JL}$	20							K/W
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +150							$^\circ\text{C}$

- Note:**
1. Measured at 1.0 MHz and applied reverse voltage of 4.0 V<sub>DC</sub>
  2. Measured with  $I_F=0.5\text{A}$ ,  $I_R=1.0\text{A}$ ,  $I_{rr}=0.25\text{A}$
  3. Mounted on P.C. Board with 8.0mm<sup>2</sup> lead area

**Ratings and Characteristics Curves**

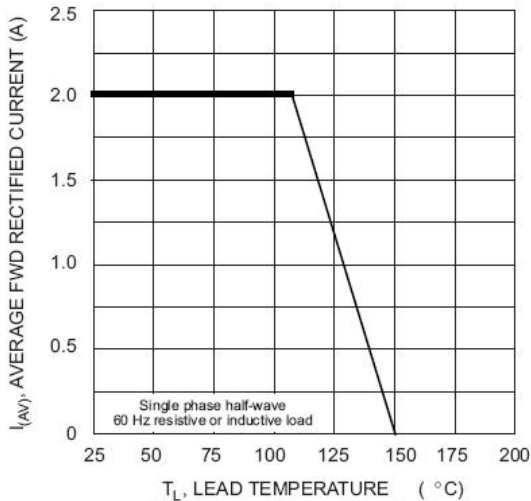


Fig. 1 Forward Current Derating Curve

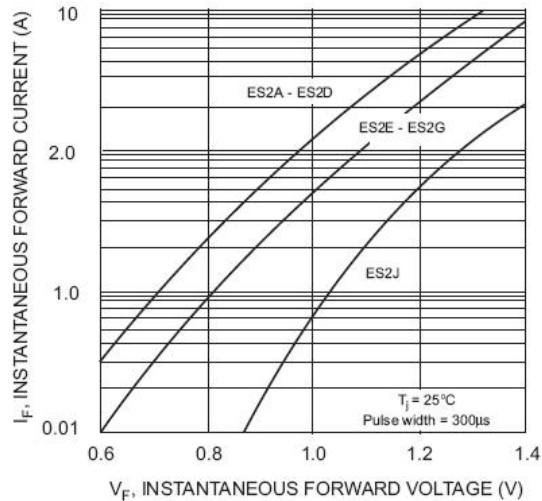


Fig. 2 Typical Forward Characteristics

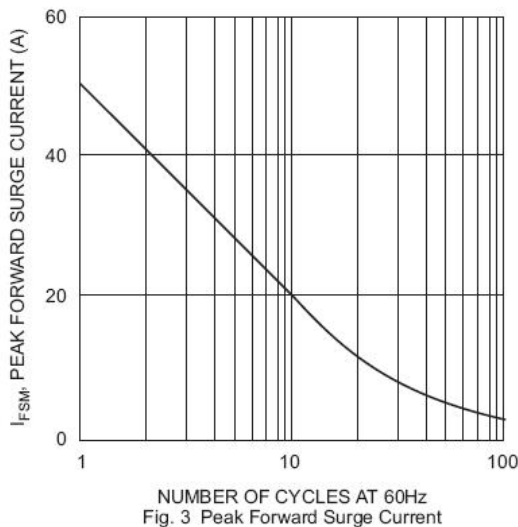


Fig. 3 Peak Forward Surge Current

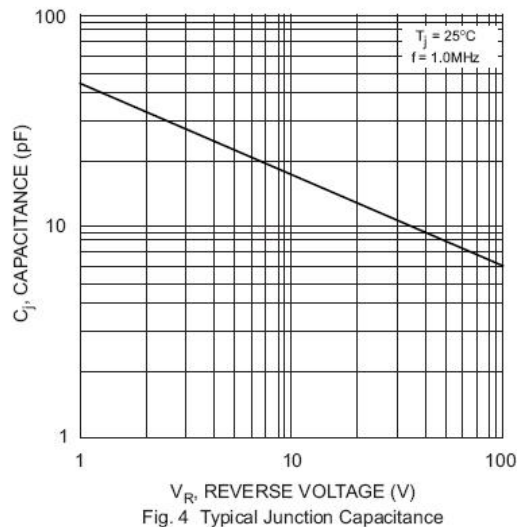
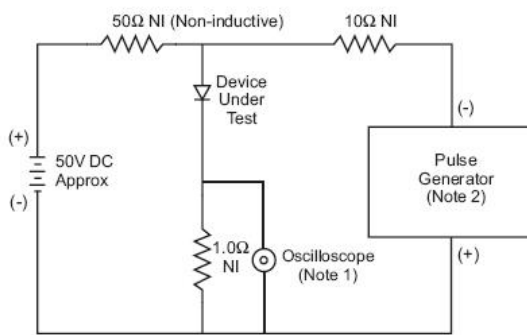


Fig. 4 Typical Junction Capacitance



Notes:  
1. Rise Time = 7.0ns max. Input Impedance = 1.0M $\Omega$ , 22pF.  
2. Rise Time = 10ns max. Input Impedance = 50 $\Omega$ .

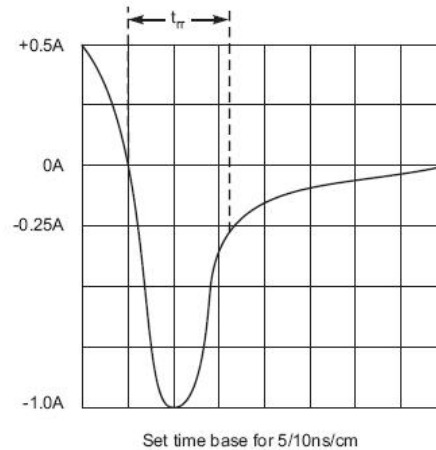
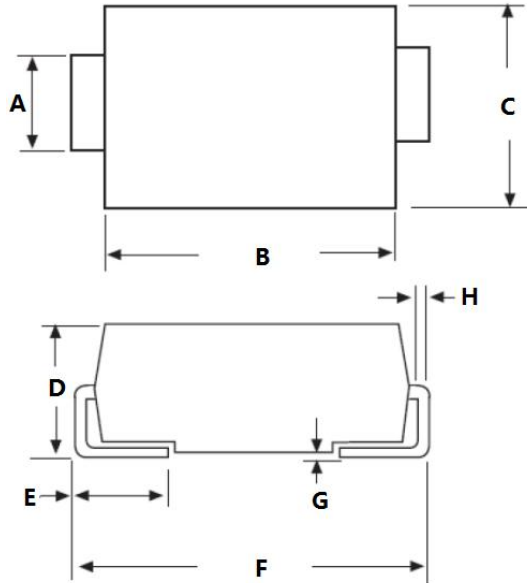


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

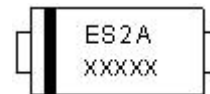
**Mechanical Dimensions SMA**


SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	1.25	1.65	0.049	0.065
B	3.95	4.60	0.156	0.181
C	2.25	2.95	0.089	0.116
D	1.95	2.90	0.077	0.114
E	0.75	1.60	0.030	0.063
F	4.80	5.60	0.189	0.220
G	0.05	0.20	0.002	0.008
H	0.15	0.41	0.006	0.016

**Ordering Information**

Device	Package	Shipping
ES2A-ES2M	SMA (Pb-Free)	5000pcs / reel

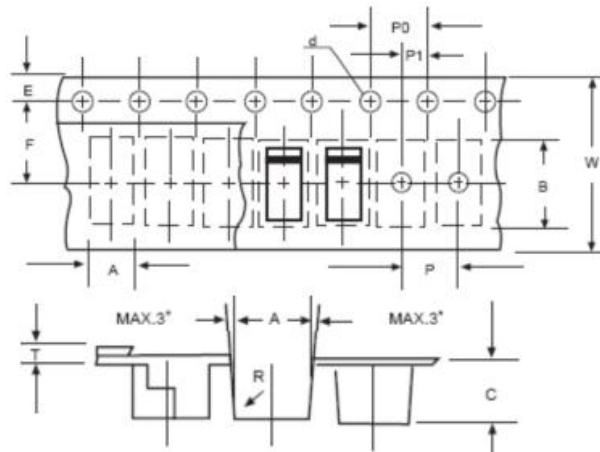
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

**Marking Diagram**


Where XXXXX is YYWWL

ES = Device Type  
 2 = Forward Current (2A)  
 A = Reverse Voltage (50V)  
 YY = Year  
 WW = Week  
 L = Lot Number

**Cautions:** Molding resin  
 Epoxy resin UL:94V-0

**Carrier Tape Specification SMA**


SYMBOL	Millimeters	
	Min.	Max.
A	2.97	3.17
B	5.70	5.90
C	2.32	2.52
d	1.40	1.60
E	1.40	1.60
F	5.60	5.70
P	3.90	4.10
P0	3.90	4.10
P1	1.90	2.10
T	0.25	0.35
W	11.80	12.20

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